

DATA SHEET

PEMH13; PUMH13
NPN/NPN resistor-equipped
transistors; $R1 = 4.7 \text{ k}\Omega$, $R2 = 47 \text{ k}\Omega$

Product data sheet
Supersedes data of 2003 Nov 07

2004 Apr 14

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FEATURES

- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs.

APPLICATIONS

- Low current peripheral driver
- Replacement of general purpose transistors in digital applications
- Control of IC inputs.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	TYP.	MAX.	UNIT
V_{CEO}	collector-emitter voltage	—	50	V
I_o	output current (DC)	—	100	mA
TR1	NPN	—	—	—
TR2	NPN	—	—	—
R1	bias resistor	4.7	—	kΩ
R2	bias resistor	47	—	kΩ

DESCRIPTION

NPN/NPN resistor-equipped transistors (see "Simplified outline, symbol and pinning" for package details).

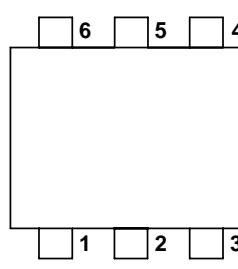
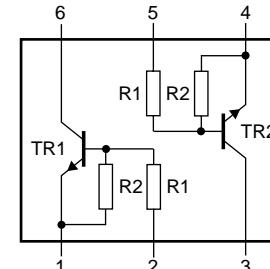
PRODUCT OVERVIEW

TYPE NUMBER	PACKAGE		MARKING CODE	PNP/PNP COMPLEMENT	NPN/PNP COMPLEMENT
	PHILIPS	EIAJ			
PEMH13	SOT666	—	21	PEMB13	PEMD13
PUMH13	SOT363	SC-88	H0*(1)	PUMB13	PUMD13

Note

1. * = p: Made in Hong Kong.
- * = t: Made in Malaysia.
- * = W: Made in China.

SIMPLIFIED OUTLINE, SYMBOL AND PINNING

TYPE NUMBER	SIMPLIFIED OUTLINE AND SYMBOL	PINNING	
		PIN	DESCRIPTION
PEMH13 PUMH13	  Top view MHC650	1 2 3 4 5 6	emitter TR1 base TR1 collector TR2 emitter TR2 base TR2 collector TR1

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ORDERING INFORMATION

TYPE NUMBER	PACKAGE		
	NAME	DESCRIPTION	VERSION
PEMH13	–	plastic surface mounted package; 6 leads	SOT666
PUMH13	–	plastic surface mounted package; 6 leads	SOT363

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per transistor					
V _{CBO}	collector-base voltage	open emitter	–	50	V
V _{CEO}	collector-emitter voltage	open base	–	50	V
V _{EBO}	emitter-base voltage	open collector	–	10	V
V _I	input voltage positive negative		–	+30	V
–			–	–5	V
I _O	output current (DC)		–	100	mA
I _{CM}	peak collector current		–	100	mA
P _{tot}	total power dissipation SOT363 SOT666	T _{amb} ≤ 25 °C note 1 notes 1 and 2	–	200	mW
–			–	200	mW
T _{stg}	storage temperature		–65	+150	°C
T _j	junction temperature		–	150	°C
T _{amb}	operating ambient temperature		–65	+150	°C
Per device					
P _{tot}	total power dissipation SOT363 SOT666	T _{amb} ≤ 25 °C note 1 notes 1 and 2	–	300	mW
–			–	300	mW

Notes

1. Device mounted on an FR4 printed-circuit board, single-sided copper, standard footprint.
2. Reflow soldering is the only recommended soldering method.

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THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
Per transistor				
$R_{th(j-a)}$	thermal resistance from junction to ambient SOT363 SOT666	$T_{amb} \leq 25 \text{ }^{\circ}\text{C}$ note 1 notes 1 and 2	625 625	K/W K/W
Per device				
$R_{th(j-a)}$	thermal resistance from junction to ambient SOT363 SOT666	$T_{amb} \leq 25 \text{ }^{\circ}\text{C}$ note 1 notes 1 and 2	416 416	K/W K/W

Notes

1. Device mounted on an FR4 printed-circuit board, single-sided copper, standard footprint.
2. Reflow soldering is the only recommended soldering method.

CHARACTERISTICS

$T_{amb} = 25 \text{ }^{\circ}\text{C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Per transistor						
I_{CBO}	collector-base cut-off current	$V_{CB} = 50 \text{ V}$; $I_E = 0 \text{ A}$	–	–	100	nA
I_{CEO}	collector-emitter cut-off current	$V_{CE} = 30 \text{ V}$; $I_B = 0 \text{ A}$	–	–	1	μA
		$V_{CE} = 30 \text{ V}$; $I_B = 0 \text{ A}$; $T_j = 150 \text{ }^{\circ}\text{C}$	–	–	50	μA
I_{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}$; $I_C = 0 \text{ A}$	–	–	170	μA
h_{FE}	DC current gain	$V_{CE} = 5 \text{ V}$; $I_C = 10 \text{ mA}$	100	–	–	
V_{CEsat}	collector-emitter saturation voltage	$I_C = 5 \text{ mA}$; $I_B = 0.25 \text{ mA}$	–	–	100	mV
$V_{i(off)}$	input-off voltage	$V_{CE} = 5 \text{ V}$; $I_C = 100 \mu\text{A}$	–	0.6	0.5	V
$V_{i(on)}$	input-on voltage	$V_{CE} = 0.3 \text{ V}$; $I_C = 5 \text{ mA}$	1.3	0.9	–	V
$R1$	input resistor		3.3	4.7	6.1	$\text{k}\Omega$
$\frac{R2}{R1}$	resistor ratio		8	10	12	
C_c	collector capacitance	$V_{CB} = 10 \text{ V}$; $I_E = i_e = 0 \text{ A}$; $f = 1 \text{ MHz}$	–	–	2.5	pF

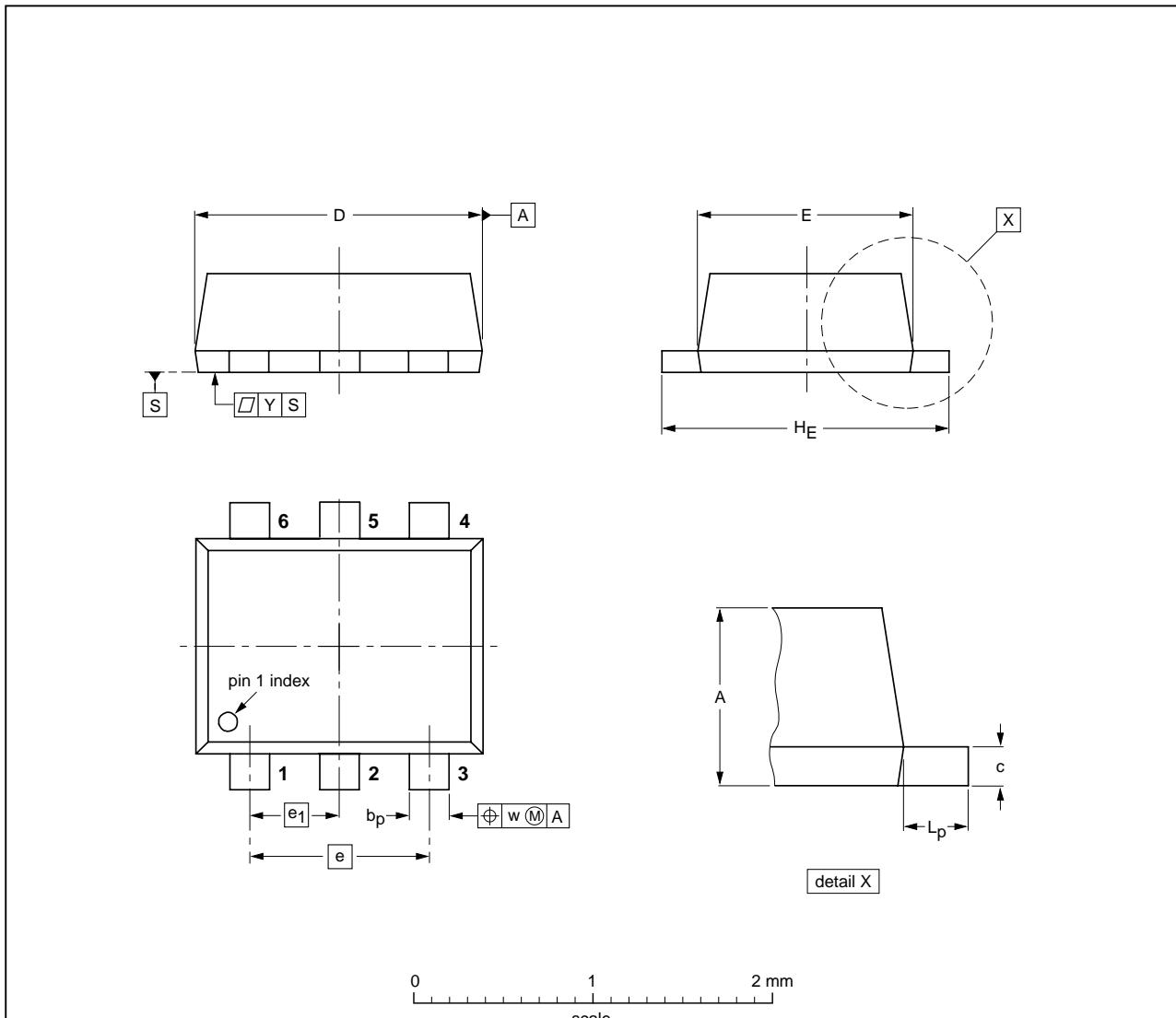
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PACKAGE OUTLINES

Plastic surface-mounted package; 6 leads

SOT666



DIMENSIONS (mm are the original dimensions)

UNIT	A	b _p	c	D	E	e	e ₁	H _E	L _p	w	y
mm	0.6	0.27	0.18	1.7	1.3	1.0	0.5	1.7	0.3	0.1	0.1
	0.5	0.17	0.08	1.5	1.1			1.5	0.1		

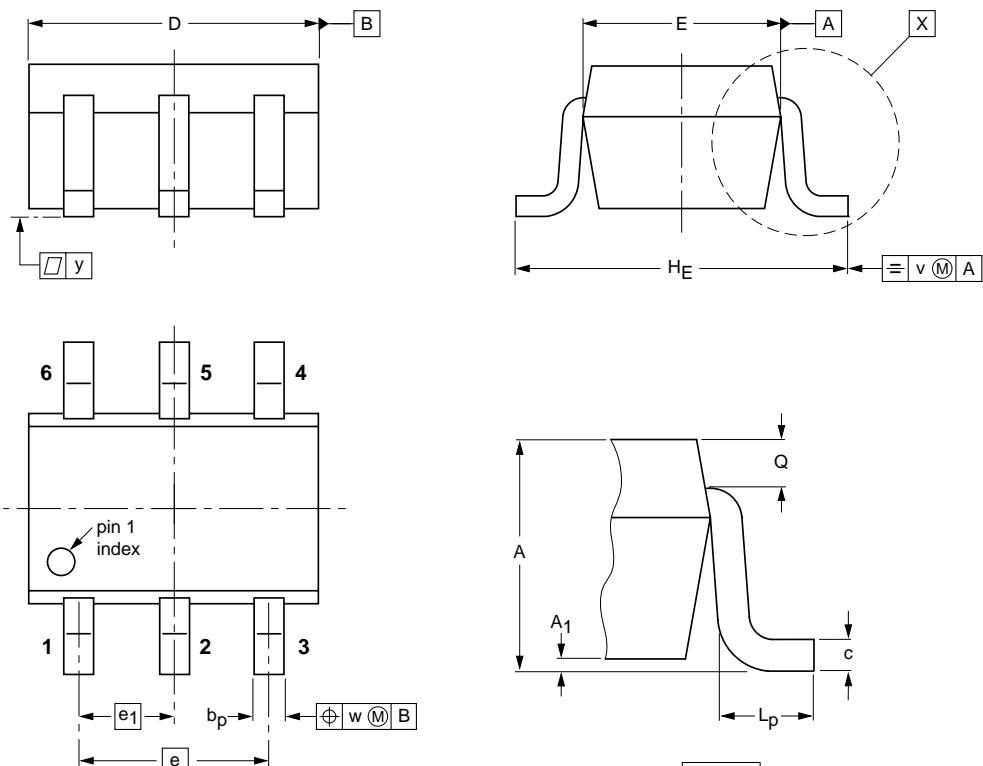
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT666						-04-11-08- 06-03-16

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SOT363



0 1 2 mm
scale

DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁ max	b _p	c	D	E	e	e ₁	H _E	L _p	Q	v	w	y
mm	1.1 0.8	0.1	0.30 0.20	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.25 0.15	0.2	0.2	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT363			SC-88			04-11-08- 06-03-16

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DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

1. Please consult the most recently issued document before initiating or completing a design.
2. The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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NXP Semiconductors

Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

Contact information

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